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Walukiewicz et al.

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(54) **MULTI-COLOR LIGHT EMITTING DEVICES WITH COMPOSITIONALLY GRADED CLADDING GROUP III-NITRIDE LAYERS GROWN ON SUBSTRATES**

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(71) Applicant: **ROSESTREET LABS ENERGY, INC.**, Phoenix, AZ (US)

(72) Inventors: **Wladyslaw Walukiewicz**, Kensington, CA (US); **Iulian Gherasoiu**, Gilbert, AZ (US); **Lothar Reichertz**, Berkeley, CA (US)

(58) **Field of Classification Search**
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See application file for complete search history.

(73) Assignee: **RoseStreet Labs Energy, Inc.**, Phoenix, AZ (US)

(56) **References Cited**

(*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 0 days.

U.S. PATENT DOCUMENTS

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(74) Attorney, Agent, or Firm — Greenberg Traurig, LLP

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(57) **ABSTRACT**

A light emitting device includes a substrate, multiple n-type layers, and multiple p-type layers. The n-type layers and the p-type layers each include a group III nitride alloy. At least one of the n-type layers is a compositionally graded n-type group III nitride, and at least one of the p-type layers is a compositionally graded p-type group III nitride. A first ohmic contact for injecting current is formed on the substrate, and a second ohmic contact is formed on a surface of at least one of the p-type layers. Utilizing the disclosed structure and methods, a device capable of emitting light over a wide spectrum may be made without the use of phosphor materials.

(51) **Int. Cl.**

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15 Claims, 4 Drawing Sheets

